

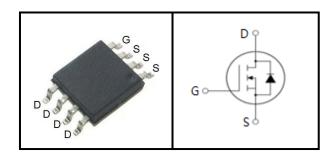
100V N-Channel DTMOS

FEATURES

- Trench Power DTMOS technology
- Low R_{DS(ON)}
- Low Gate Charge
- Optimized for fast-switching applications

APPLICATIONS

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial





Device Marking and Package Information			
Device	Package	Marking	
TSJ10N10AT	SOP-8	10N10AT	

Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted				
Parameter	Symbol	Value	Unit	
Drain-Source Voltage (V _{GS} = 0V)	V _{DSS}	100	V	
Continuous Drain Current	I _D	8	А	
Pulsed Drain Current (note1)	I _{DM}	32	А	
Gate-Source Voltage	V _{GSS}	±20	V	
Single Pulse Avalanche Energy (note2)	E _{AS}	10	mJ	
Avalanche Current (note1)	I _{AS}	14	A	
Power Dissipation ($T_c = 25^{\circ}C$)	P _D	3.1	W	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C	

Thermal Resistance			
Parameter	Symbol	Value	Unit
Junction-to-Drain Lead	R _{thJC}	24	°C/W
Thermal Resistance, Junction-to-Ambient	R _{th.IA}	40	1



TSJ10N10AT

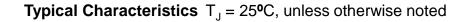
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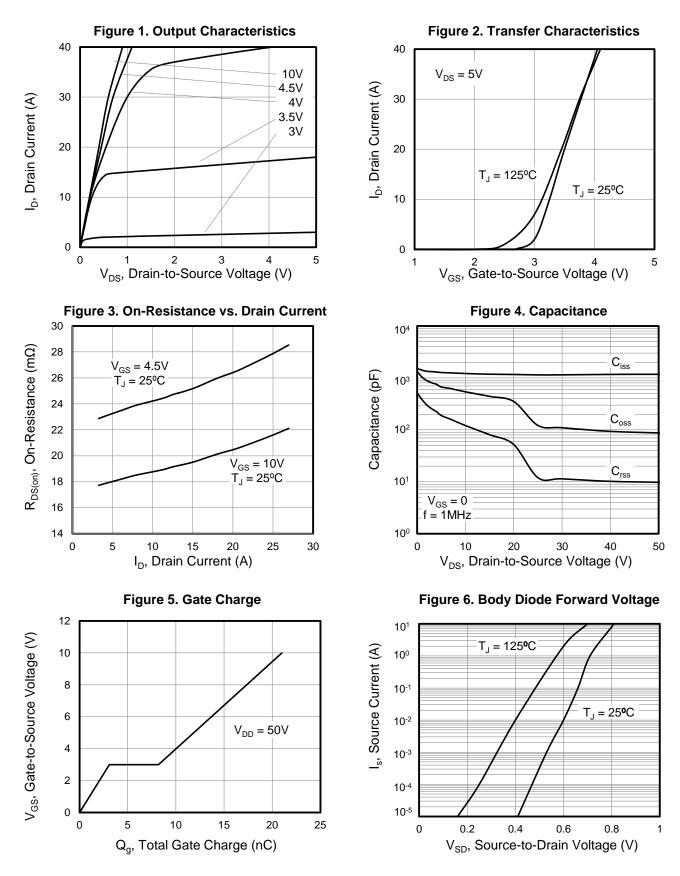
Specifications $T_J = 25^{\circ}C$, ur	less othe	rwise noted			i	
Parameter	Symbol	Test Conditions	Value			Unit
	eyee.		Min.	Тур.	Max.	Onic
Static			_			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250 \mu A$	100			V
	I _{DSS}	$V_{DS} = 95V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	
Zero Gate Voltage Drain Current		$V_{DS} = 95V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100	μA
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 20V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.1		2.5	V
Drain Source On Desistence (Note2)	Р	$V_{GS} = 10V, I_{D} = 8A$		19		
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 4.5 V, I_{D} = 6 A$		23	33	mΩ
Forward Transconductance (Note3)	g _{fs}	$V_{DS} = 5V, I_D = 1A$		30		S
Dynamic			-			
Input Capacitance	C _{iss}			1134		pF
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 50V,$		92		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		10.3		
Total Oata Obarra	Q _g (10V)			21		nC
Total Gate Charge	Q _g (4.5V)	V _{DD} = 50V, I _D = 8A,		11		
Gate-Source Charge	Q _{gs}	$V_{GS} = 10V$		3.1		
Gate-Drain Charge	Q_{gd}			5.1		
Turn-on Delay Time	t _{d(on)}			7		
Turn-on Rise Time	t _r	V _{DD} = 50V, I _D = 8A,		3		ns
Turn-off Delay Time	t _{d(off)}	$R_{G} = 3\Omega$		20		
Turn-off Fall Time	t _f			3		
Drain-Source Body Diode Characteri	stics					
Continuous Body Diode Current	I _S	T 0500			4	
Pulsed Diode Forward Current	I _{SM}	$T_{\rm C} = 25^{\circ}{\rm C}$			12	A
Body Diode Voltage	V_{SD}	$T_{J} = 25^{o}C, I_{SD} = 1A, V_{GS} = 0V$		0.72	1	V
Reverse Recovery Time	t _{rr}	I _F = 8A,		20		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt = 500A/µs		90		nC

Notes

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. I_{AS} = 14A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1%
- 4. When mounted on 1" in square copper board







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Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

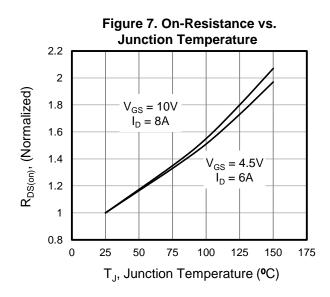
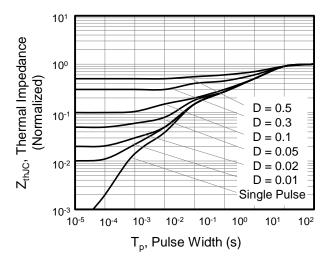
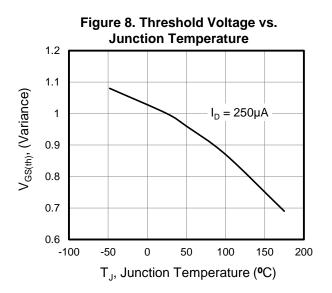
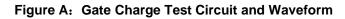


Figure 9. Transient Thermal Impedance







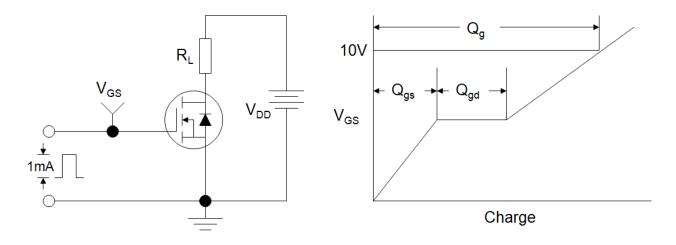


Figure B: Resistive Switching Test Circuit and Waveform

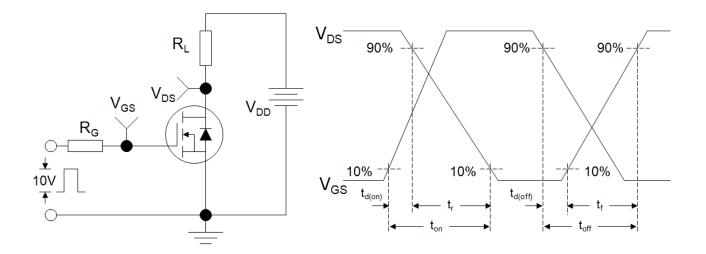
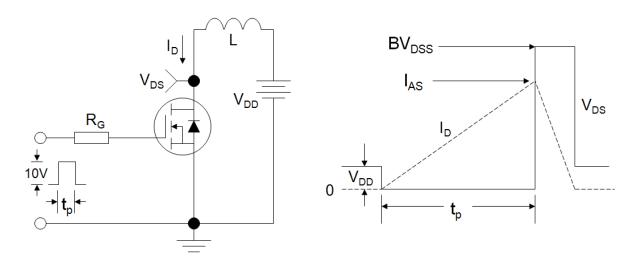


Figure C: Unclamped Inductive Switching Test Circuit and Waveform

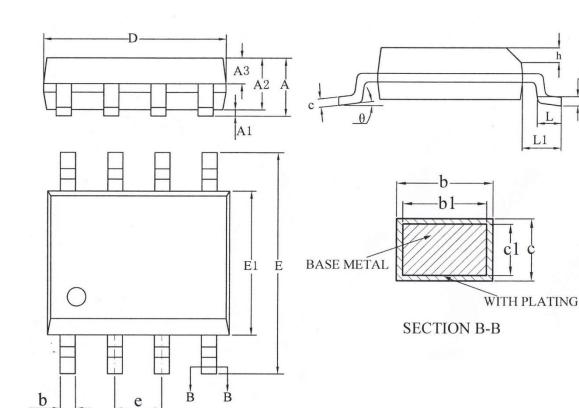


h

0.25

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SOP-8

SYMBOL	MILLIMETER			
	MIN	NOM	MAX	
А			1.75	
A1	0.10		0.225	
A2	1.30	1.40	1.50	
A3	0.60	0.65	0.70	
b	0.39		0.48	
b1	0.38	0.41	0.43	
с	0.21		0.26	
c1	0.19	0.20	0.21	

e

SYMDOL	MILLIMETER			
SYMBOL	MIN	NOM	MAX	
D	4.70	4.90	5.10	
Е	5.80	6.00	6.20	
E1	3.70	3.90	4.10	
e	1.27BSC			
h	0.25		0.50	
L	0.50		0.80	
L1	1.05BSC			
θ	0		8°	



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